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Nanodiamond embedded ta-C composite film by pulsed filtered vacuum arc deposition from a single target

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Detonation Nanodiamonds (DNDs) are known to have sp³ core, sp² shell, small size (few nm) and are gaining importance as multi-functional nanoparticles. Diverse methods have been used to form composites, containing detonation nanodiamonds (DNDs) embedded in conductive and dielectric matrices for various applications. Here we show a method, wherein DND-ta-C composite film, consisting of DNDs embedded in ta-C matrix have been co-deposited from the same cathode by pulsed filtered cathodic vacuum arc method. Transmission Electron Microscope analysis of these films reveal the presence of DNDs embedded in the matrix of amorphous carbon. Raman spectroscopy indicates that the presence of DNDs does not adversely affect the sp³ content of DND-ta-C composite film compared to ta-C film of same thickness. Nanoindentation and nanowear tests indicate that DND-ta-C composite films possess improved mechanical properties in comparison to ta-C films of similar thickness. Published by AIP Publishing. [http://dx.doi.org/10.1063/1.4967985]

Nanodiamonds (NDs) have found wide fields of applications due to the presence of stable diamond core, leading to versatile properties. However, growth of nanodiamonds on any surface is generally achieved by chemical vapour deposition (CVD) at elevated temperatures. In many cases, such high temperature processes cannot be performed due to substrate considerations or in cases where the NDs need to be embedded in a matrix. Thus, it is easier to proceed from pre-made NDs, such as those synthesized by a detonation process. Detonation nanodiamonds (DNDs) have a diamond core surrounded by sp² carbon shell which can easily be functionalized for a variety of applications. It has been shown that incorporation of DNDs in an epoxy matrix or metal matrix can result in improved mechanical properties of the composite. However, making any hard, thin film coating with NDs alone, without embedding them in a matrix material, is impossible.

Diamond like Carbon (DLC) is an amorphous carbon coating which is very hard and is used as a mechanical coating at an industrial scale, with Tetrahedral Amorphous Carbon (ta-C) being the best possible DLC coating. DLC/ta-C films with NDs have been fabricated either by depositing the NDs before DLC/ta-C film growth or by CVD methods at high temperature, where process parameters must be varied to cater for nucleation of NDs and DLC separately.

In this publication, we present a method of co-depositing DNDs and ta-C from the same cathode using a pulsed filtered cathodic vacuum arc process (p-FCVA) at ambient temperatures. In essence, the carbon cathode was loaded with DNDs some of which were ejected in the process of carbon arc plasma formation. Without going into the details of cathodic arcs at the arc spot, carbon cathode gets converted into plasma with nano and micro particles which was directed to the substrate through a macro-particle filter. The ejected DNDs travel in the carbon plasma stream and are not filtered by the macro-particle filter if they are few tens to few hundreds of nm in size. On the substrate, the DNDs get embedded in the growing ta-C film forming a nano-composite film by a one-step deposition process operating at room temperature.

The deposition system consists of a vacuum chamber which can be evacuated to pressures lower than 2 × 10⁻⁷ Torr (2.66 × 10⁻⁵ Pa). The p-FCVA system uses a 45° bent filter, with a pulse forming network charged to ~400 V (pulse current 650 A) to initiate the arc between the cathode and anode. The triggerless arc was initiated in pulses, at a repetition frequency of 1.0 Hz, by use of a self-designed Labview based software, controlling National Instruments (NI) hardware.

Graphite rods of diameter 6.35 mm and purity of 99.995% (Graphitestore) were used as cathodes and charged with DNDs. The DNDs in stable water suspension (Andante™) with 5 wt. % of DNDs and average single digit size of 5 nm (Carbodeon Ltd) was used to charge the cathodes. The carbon cathode was drilled with 7 holes (hole diameter 1.5 mm and hole depth 3 mm) distributed over the cathode area. 100 µl of DND solution was drop cast into the holes following which the graphite rod was dried on a hot plate at 200°C for 120 min. After the 120 min drying time, the graphite rod was allowed to cool, and the charging procedure was repeated once more.

Intrinsic silicon (100) cut into 3 cm × 2 cm was used as substrates. The substrates were ultrasonically cleaned in high purity liquid chromatography (HPLC) grade acetone and blow dried by N₂ gas. For TEM analysis, salt crystals (Tedpella) cleaved into 1 cm × 1 cm pieces and ultrasonically cleaned by HPLC grade acetone were used as substrates. Post deposition, the salt crystals were put as the film sides up in a shallow bath of de-ionized water until the film delaminates. The delaminated film was fished out onto M75 copper only TEM grids (Agar) and used for TEM analysis. For comparative TEM analysis original DND solution was...
diluted to 0.05 wt. % and drop cast onto 400 mesh copper grids with holey carbon film (Agar). Film thickness of 50 nm (500 pulses) was deposited for both ta-C and DND-ta-C for comparative analysis. The substrate was placed 110 mm away from the plasma filter coil at floating potential and room temperature. The substrate was rotated at 17 rpm to ensure uniform film thickness over the whole area. The deposition rate for both ta-C and DND-ta-C composite film was found to be around 0.1 nm/pulse for 110 mm substrate to filter coil distance by checking the film thickness using a contact profilometer (Dektak 6M).

TEM analysis was performed by a Tecnai F-20 (FEI) TEM operating at 200 kV and acquired images were processed by Digital Micrograph software (Gatan). SEM analysis of the samples was performed by a Hitachi S-4700 SEM. Raman spectroscopy was performed by a Labram HR (Horiba Jobin-Yvon) confocal Raman system (Ar laser λ = 488 nm and power = 10 mW) using 100× objective.

FIG. 1. HRTEM images and SAED ring patterns of samples. (a) HRTEM image of original DND solution; (b) SAED ring pattern of original DND solution indexed to cubic diamond phase (marked in red); (c) HRTEM image of DND-ta-C composite film. The DND particles are marked. The amorphous film in the image is ta-C; (d) SAED ring pattern of DND-ta-C composite film from DND agglomerate indexed to cubic diamond phase (marked in red); (e) FFT of the area indicated by red square in (c). The cubic diamond phase is marked; (f) Particle size histogram for 50 particles from HRTEM image analysis.
with a spot size of around 1 \( \mu \)m and aperture size of 1000 \( \mu \)m to maximize the signal from DNDs.

Nano wear and Nano indentation tests were performed using a TI-900 (Hysitron Inc.) system using a Berkowitz tip (nominal diameter 200 nm). For both the DND-ta-C and reference ta-C films, to reduce contribution of the silicon substrate, the nano-indentation testing was performed in two stages. In the first stage, 10 point indentation was performed to estimate the optimal depth from load-displacement curves. In the second stage, an untouched area was selected and 12 points were indented in a displacement controlled manner set for the optimal depth as found from the previous stage. Wear tests were performed at 4 points with loads of 50 \( \mu \)N to 200 \( \mu \)N with increments of 50 \( \mu \)N for every point. Each wear point scan area was 1 \( \mu \)m \( \times \) 1 \( \mu \)m, and tests were performed with 2 and 4 wear scan passes to compare the wear with increase in number of scan passes. Post wear images were acquired by using a small force of 1.5 \( \mu \)N, and the image area was 3 \( \mu \)m \( \times \) 3 \( \mu \)m.

The wear images were analysed by Gwyddion and the average crater wear volume was calculated as a product of the average crater wear depth and the average crater area for each load. The wear volume ratio was calculated as the ratio of the average crater wear volume to the maximum possible wear volume (film thickness \( \times \) 1 \( \mu \)m2).

Cross-sectional SEM images (not shown) of the DND-ta-C film, indicate the film thickness to be around 55 \( \pm \) 3 nm which compares well with the expected film thickness of 50 nm.

The representative HRTEM image and selected area electron diffraction (SAED) ring pattern from the original DND solution drop cast onto the TEM grid are shown in Figs. 1(a) and 1(b). From the SAED ring pattern of the original DNDs (indexed in Fig. 1(b) and Table I), the primary d-spacings were found to be 2.09 Å, 1.25 Å, and 1.07 Å, which matches closely with values in literature for cubic diamond nanoparticles. Representative HRTEM image of the DND-ta-C composite film (Fig. 1(c)) indicates DND agglomerate embedded (marked in image) in a matrix of amorphous ta-C. The SAED ring pattern from a DND agglomerate in the DND-ta-C composite film (indexed in Fig. 1(d) and tabulated in Table I) indicates a cubic diamond phase. The cubic diamond phase can also be observed from the FFT of HRTEM image as shown in Fig. 1(e). It must be pointed out that the SAED ring patterns from the majority of the composite film area consist of partial rings with a weak intensity, indicating the presence of DNDs. This is attributed to the extremely small size (average diameter of 5 nm) and low concentration of DNDs in the composite film. Complete SAED ring patterns are observed with larger DND agglomerate (a few tens of nm) as shown in Fig. 1(d). Similarly stable and high quality HRTEM images could be obtained only for larger DND agglomerates while individual DNDs were graphitized in a short time when exposed to the electron beam. The graphitization time and extent is dependent on the size of the DNDs and the smaller DNDs graphitize faster than the large agglomerates. The SAED ring patterns from reference ta-C film (not shown) are typical of amorphous films and show no crystallinity whatsoever. Energy dispersive X-ray spectroscopy (EDX) performed using a small electron beam probe on a large number of particles in the DND-ta-C film (results not shown here) indicated only carbon K\( \alpha \) line as the relevant peak in the spectrum. Particle analysis from the

<table>
<thead>
<tr>
<th>Cubic Diamond15–17 d (Å) [hkl]</th>
<th>Original DND solution d measured (Å)</th>
<th>DND-ta-C composite d measured (Å)</th>
</tr>
</thead>
<tbody>
<tr>
<td>2.06 {111}</td>
<td>2.09</td>
<td>2.10</td>
</tr>
<tr>
<td>1.26 {220}</td>
<td>1.25</td>
<td>1.23</td>
</tr>
<tr>
<td>1.07 {311}</td>
<td>1.07</td>
<td>1.06</td>
</tr>
<tr>
<td>0.89 {400}</td>
<td>0.88</td>
<td>0.90</td>
</tr>
<tr>
<td>0.81 {331}</td>
<td>0.81</td>
<td>0.81</td>
</tr>
<tr>
<td>0.72 {422}</td>
<td>0.71</td>
<td>0.71</td>
</tr>
<tr>
<td>0.68 {511}</td>
<td>0.68</td>
<td>...</td>
</tr>
</tbody>
</table>

FIG. 2. Raman spectra acquired at 488 nm wavelength. (a) Reference ta-C 50 nm thick; (b) DND-ta-C 50 nm thick.
films, indicating that the sp³ ratio of the films are unaffected. There is a substantial difference between reference ta-C and DND-ta-C films. The I(D)/I(G) ratios show no substantial plots are shown in Fig. 2. The I(D)/I(G) ratios for the DND-ta-C film as a function of load plotted for 4 scan passes.

HRTEM images indicates an average of around 17 000 DNDs per µm³, dispersed as small agglomerates (Fig. 1(f)). From the particle analysis, the DND concentration was calculated to be on the order of 0.1 vol. % in the DND-ta-C film.

Raman spectra for both reference ta-C and DND-ta-C film were acquired and fitted by two peaks for D and G regions of amorphous carbon as per literature and representative plots are shown in Fig. 2. The I(D)/I(G) ratios for both the 50 nm thick films were calculated from 3 random points each and averaged. The I(D)/I(G) ratios show no substantial difference between reference ta-C and DND-ta-C film, indicating that the sp³ ratio of the films are unaffected by the DNDs. Note that the DND peaks (expected around 1325–1332 cm⁻¹) are not visible in the Raman spectra, most probably due to the low concentration of DNDs in the ta-C matrix (as shown above) and heavy attenuation of the sp³ signal due to sp² content in the ta-C film.10,19

The nano-indentation data was analysed by Hysitron Inc. software using Oliver-Pharr method.20 The tip area function was calibrated before and after the indentation and wear tests. For both samples the average value of hardness was calculated by averaging the 12 point hardness data and further averaged for tip area function. The average hardness for reference ta-C film is around 30 GPa, which matches with the data in Refs. 10 and 21 while for the DND-ta-C film, the average hardness is around 35 GPa. The wear volume ratio plots for 2 and 4 wear scans are shown in Figs. 3(a) and 3(b), respectively. It can be observed from the wear volume ratio plots (Fig. 3) that the wear volume ratio of reference ta-C film increases sharply as the load and number of passes increase while, the DND-ta-C film wear volume ratio has only a modest increase over the whole range of loads and passes. From the DND concentration, we estimate that there would be few tens of DNDs below the indenter tip at any given position and time. The presence of embedded DNDs appears to improve the mechanical properties of the DND-ta-C film as the nano-indentation data indicates that the DND-ta-C is harder and more wear resistant than reference ta-C.

In summary, we have shown a method of co-depositing DND embedded ta-C composite thin films by a single step, room temperature p-FCVA process. The TEM analysis of DND-ta-C composite film indicates the presence of DNDs embedded in the ta-C matrix. The small quantity of DNDs (on the order of 0.1 vol. %) in the DND-ta-C composite film, seems to have no effect on the sp³ ratio of the film, but the composite film is observed to be harder and more wear resistant than ta-C film of the same thickness. Also cyclic voltammetry tests indicate that the already fabricated DND-ta-C composite film is a very sensitive bio-sensor film, and further tests are in progress.

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